| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|----------|-------|--|---|---------------------|---------|------------------|
| S33 | 4391 | (nitride or "silicon nitride" or "Si. sub.3N.sub.4") same ("bit line" or bit-line) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/20 12:42 |
| S34 | 794 | @ad<="19970610" and S33 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/20 12:43 |
| S35 | 13639 | (nitride or "silicon nitride" or "Si. sub.3N.sub.4") and ("bit line" or bit-line) | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/20 12:42 |
| S36 | 3019 | @ad<="19970610" and S35 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/20 12:43 |
| S37 | 2871 | semiconductor and S36 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/20 12:43 |
| S38 | 1860 | capacitor and S37 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/20 12:43 |
| S39 | 1330 | S38 not S34 | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2005/09/20 12:44 |